

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Ching-Shi Jenq et al.

Serial No.: Not Yet Assigned

Group Art Unit: Unknown

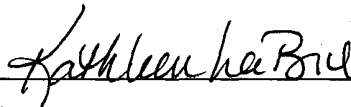
Filed: Herewith

Examiner: Unknown

Title: **A SCALABLE FLASH EEPROM MEMORY CELL WITH FLOATING GATE SPACER WRAPPED BY CONTROL GATE, AND METHOD OF MANUFACTURING THE SAME**

EXPRESS MAIL NUMBER: EV 302 277 483 DATE OF DEPOSIT: July 9, 2003

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PRELIMINARY AMENDMENT

Commissioner for Patents
Washington, DC. 20231

ATTN: BOX PATENT APPLICATION

Sir:

Prior to examination of the above-identified application, which is a divisional of application serial number 10/005,495 filed on November 6, 2001, please amend the application as follows:

In the Title:

Please amend the title to read:

--METHOD OF MANUFACTURING A SCALABLE FLASH EEPROM MEMORY
CELL WITH FLOATING GATE SPACER WRAPPED BY CONTROL GATE --